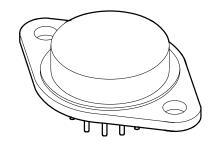


DUAL HIGH POWER OP-AMP

2541

FEATURES:

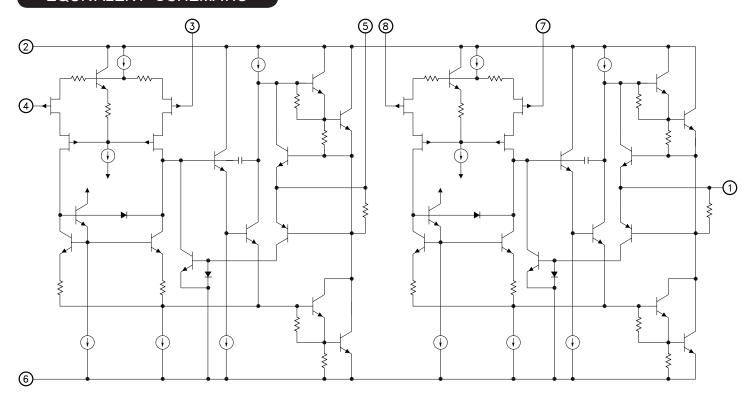
- Available as SMD #5962-9083801 HX and 5962-9083803HX
- · High Output Current 10 Amps Peak
- Wide Power Supply Range ±10V to ±40V
- · On Board Current Limit
- FET Input
- · Isolated Case
- · Second Source for OMA 2541SKB



DESCRIPTION:

The MSK2541 is a high power dual monolithic amplifier ideally suited for high power amplification and magnetic deflection applications. This amplifier is capable of operation at a supply voltage rating of 80 volts and can deliver guaranteed continuous output currents up to 5A per amplifier. The MSK2541 has internal current limit circuitry to protect the amplifier and load from transients. The MSK2541 is available in a hermetically sealed 8 pin TO3 package that is isolated from internal circuitry. This allows for convenient bolt down heat sinking when necessary.

EQUIVALENT SCHEMATIC



TYPICAL APPLICATIONS

- · Servo Amplifer
- · Motor Driver
- · Audio Amplifier
- Programmable Power Supply
- · Bridge Amplifier

PIN-OUT INFORMATION

- 1 Output B
- 2 Positive Power Supply
- 3 Non-Inverting Input A
- 4 Inverting Input A
- 8 Inverting Input B
- 7 Non-Inverting Input B
- 6 Negative Power Supply
- 5 Output A

ABSOLUTE MAXIMUM RATINGS

±Vcc	Voltage Supply	±40V
lout	Peak Output Current	See S.O.A.
VIN	Differential Input Voltage	±Vcc
VIN	Common Mode Input Voltage	±Vcc
Tc	Case Operating Temperature Range	
	MSK2541B	55°C to +125°C
	MSK2541	40° to +85°C

Tst	Storage Temperature Range1165°C to +	-150°C
TLD	Lead Temperature Range	
	(10 Seconds)	300°C
TJ	Junction Temperature	150°C

ELECTRICAL SPECIFICATIONS

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Parameter	Test Conditions	Group A	MSK2541B			MSK2541 (5)			Units
	Tost conditions	Subgroup	Min.	Тур.	Max.	Min.	Тур.	Max.	Omto
STATIC									
Supply Voltage Range 2 4		-	±10	±35	±40	±10	±35	±40	V
Quiescent Current	Total - Both Amplifiers Vเท = 0V	1, 2, 3	-	±40	±60	-	±40	±60	mA
INPUT									
Input Offset Voltage	VIN = 0V	1	-	±0.1	±1.5	-	±1.0	±10	mV
Input Offset Voltage Drift	VIN = 0V	2, 3	-	±15	±50	-	±15	-	μV/°C
Input Bias Current (4)	Vcm = 0V	1	-	±4	±50	-	±4	±100	pА
Input Bias Current (4)	Either Input	2, 3	-	±10	±150	-	±10	-	nA
Input Offset Current (4)	VcM = 0V	1	-	2.0	30	-	2.0	30	pΑ
Input Offset Guiterit (4)	V CIVI — U V	2, 3	-		50	-	-	-	nA
Input Capacitance		-	-	5	-	-	5	-	pF
Imput Impedance 4	F = DC	-	-	1012	-	-	1012	-	W
Common Mode Rejection Ratio 4	$F = DC V_{CM} = \pm 22V$	-	95	113	-	90	113	-	dB
Power Supply Rejection Ratio (4)	Vcc = ±10V to ±40V	-	-	90	-	-	90	-	dB
OUTPUT									
Output Voltage Swing	$RL = 5.6\Omega$ $F \le 10$ KHz	4	±28	±29	-	±28	±29	-	V
Output voltage Swing	$R_L = 10\Omega$ F = 10 KHz	5, 6	±30	±31	-	-	-	-	V
Output Current	RL = 5.6Ω F ≤ 10 KHz	4	±5	±8	-	±5	±8	-	Α
Output Current	$RL = 10\Omega$ F = 10 KHz	5, 6	±3.0	-	-	-	-	-	Α
Settling Time (3) (4)	0.1% 2V step	-	-	2	-	-	2	-	μS
Power Bandwidth	$RL = 10\Omega$ Vo = 20 VRMs	4	45	55	-	40	50	-	KHz
TRANSFER CHARACTERISTICS									
Slew Rate	Vout = $\pm 10V$ RL = 10Ω	4	6	10	-	6	10	-	V/µS
Open Loop Voltage Gain (4)	F = 10 Hz RL = 10 KΩ	4	95	100	-	90	100	-	dB
Open Loop Voltage Gain (4)	F = 10 HZ RL = 10 K12	5, 6	85	-	-	-	-	-	dB
THERMAL RESISTANCE 4									
θJC (Junction to Case)	One Amplifier, DC Output	-	-	1.4	1.9	-	1.9	2.2	°C/W
θJC	One Amplifier, AC Output F > 60	-	-	1.25	1.5	-	1.7	1.8	°C/W
θЈС	Both Amplifiers, DC Output	-	-	0.9	1.2	-	1.2	1.5	°C/W
θЈС	Both Amplifiers, AC Output F > 60	-	-	8.0	1.0	-	1.1	1.3	°C/W
θJA (Junction to Ambient)	No Heat Sink	-	-	30	-	-	30	-	°C/W

NOTES:

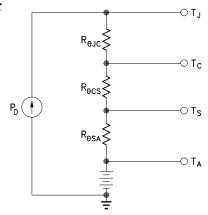
- 1 Unless otherwise specified: $\pm Vcc = \pm 34 Vcc$, all specs are per amplifier.
- 2 Electrical specifications are derated for power supply voltages other than ±34 VDC.
- 3 AV = -1, measured in false summing junction circuit.
- 4 Guaranteed by design but not tested. Typical parameters are for reference only.
- (5) Industrial grade devices shall be tested to subgroups 1 and 4 unless otherwise specified.
- 6 Military grade devices ('B' suffix) shall be 100% tested to subgroups 1, 2, 3 and 4.
- (7) Subgroup 5 and 6 testing available upon request.
- 8 Subgroup 1, 4 $TA = TC = +25^{\circ}C$
 - Subgroup 2, 5 TA = TC = +125°C
 - Subgroup 3, 6 $TA = Tc = -55^{\circ}C$
- (9) Reference DSCC SMD 5962-9083801 and 5962-9083803 for electrical specifications for devices purchased as such.
- (f) Continuous operation at or above absolute maximum ratings may adversely effect the device performance and/or life cycle.
- (1) Internal solder reflow temperature is 180°C, do not exceed.

APPLICATION NOTES

HEAT SINKING

To select the correct heat sink for your application, refer to the thermal model and governing equation below.

Thermal Model:



Governing Equation:

 $T_J = P_D X (R_{\theta JC} + R_{\theta CS} + R_{\theta SA}) + T_A$

Where

TJ = Junction Temperature
PD = Total Power Dissipation

Rejc = Junction to Case Thermal Resistance
Recs = Case to Heat Sink Thermal Resistance
ResA = Heat Sink to Ambient Thermal Resistance

Tc = Case Temperature
TA = Ambient Temperature
Ts = Sink Temperature

Example:

In our example the amplifier application requires each output to drive a 20 volt peak sine wave across a 10 ohm load for 2 amps of output current. For a worst case analysis we will treat the 2 amps peak output current as a D.C. output current. The power supplies are ± 35 VDC.

1.) Find Power Dissipation

PD = [(quiescent current) X (+Vcc - (-Vcc))] + [(Vcc - Vo) X Iout]

= (30 mA) X (70 V) + (15 V) X (2 A) + (15 V) x (2 A)

= 2.1W + 60W

= 62.1W

2.) For conservative design, set T_J = +150°C

3.) For this example, worst case TA = +25°C

4.) R₀JC = 1.2°C/W typically

5.) R₀Cs = 0.15°C/W for most thermal greases

6.) Rearrange governing equation to solve for Resa

 $R_{\theta}SA = (T_J - T_A) / P_D - (R_{\theta}J_C) - (R_{\theta}C_S)$

= $(150^{\circ}\text{C} - 25^{\circ}\text{C})/(62.1\text{W}) - (1.2^{\circ}\text{C/W}) - (0.15^{\circ}\text{C/W})$

= ≅0.66°C/W

The heat sink in this example must have a thermal resistance of no more than 0.66°C/W to maintain a junction temperature of no more than +150°C. Since this value of thermal resistance may be difficult to find, other measures may have to be taken to decrease the overall power dissipation. Refer to the "Heat Sinking Options" application note offered by MSK.

POWER SUPPLY CONNECTIONS

The MSK2541 maximum supply voltage is specified as ±40V. However, single sided or unbalanced power supply operation is permissible as long as the total power supply voltage does not exceed 80V. Caution should be exercised when routing high current printed circuit paths. Generally, these paths should not be placed near low level, high impedance input circuitry to avoid oscillations.

During prototype evaluation, power supply current limiting is strongly advised to avoid damaging the device. See the application note entitled "Current Limit" for an explanation of the limitations of the MSK2541 on board current limit.

POWER SUPPLY BYPASSING

Both the negative and the positive power supplies must be effectively decoupled with a high and low frequency bypass circuit to avoid power supply induced oscillation. An effective decoupling scheme consists of a 0.1 microfarad ceramic capacitor in parallel with a 4.7 microfarad tantalum capacitor from each power supply pin to ground. It is also a good practice with very high power op-amps, such as the MSK2541, to place a 30-50 microfarad non-electrolytic capacitor with a low effective series resistance in parallel with the other two power supply decoupling capacitors. This capacitor will eliminate any peak output voltage clipping which may occur due to poor power supply load regulation. All power supply decoupling capacitors should be placed as close to the package power supply pins as possible (pins 3 and 6).

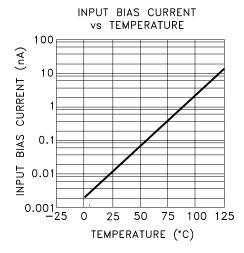
CURRENT LIMIT

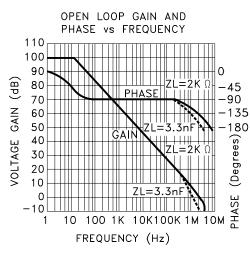
The internal current limit should not be used as a short circuit protection scheme. When the output is directly shorted to ground, the power supply voltage is applied across the output transistor that is conducting. If the power supplies were set to ±40V and the output was shorted to ground, the transistor that is conducting current would see 40V from its emitter to its collector. Referring to the safe operating area curve shows when [Vcc-Vout]=40V, the maximum safe output current (Io) at Tc=25°C is 1.5A. In this case the amplifier would not be protected by the internal current limit and would probably be damaged. The internal current limit is provided as a protection against unintentional load conditions which may require larger amounts of load current than the amplifier is rated for.

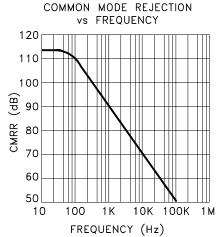
SAFE OPERATING AREA

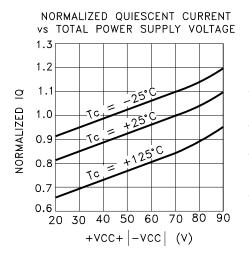
The safe operating area curve is a graphical representation of the power handling capability of the amplifier under various conditions. The wire bond current carrying capability, transistor junction temperature and secondary breakdown limitations are all incorporated into the safe operating area curves. All applications should be checked against the S.O.A. curves to ensure high M.T.T.F.

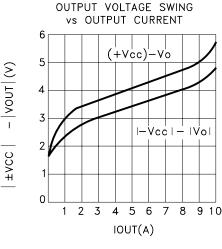
TYPICAL PERFORMANCE CURVES

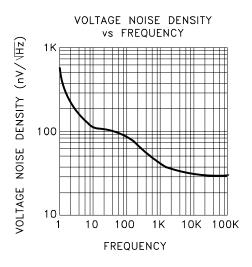


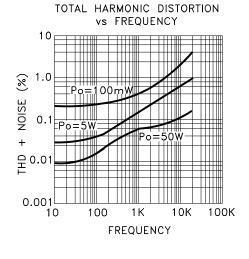


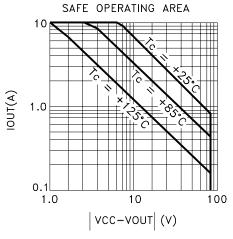


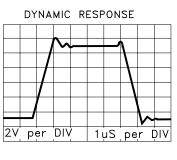






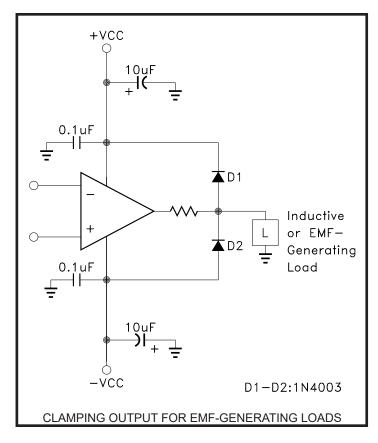


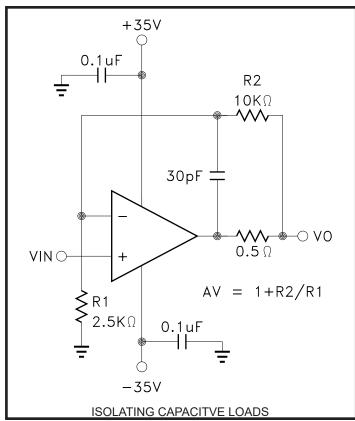


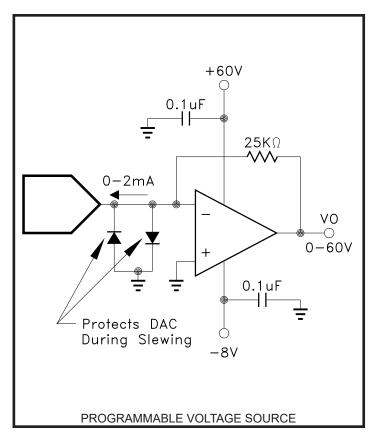


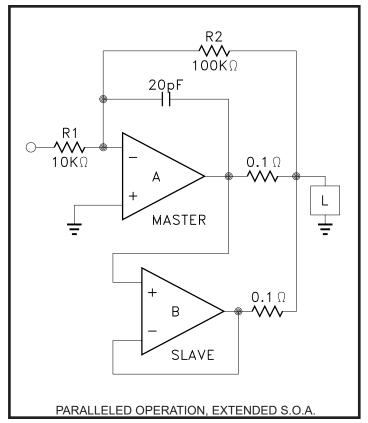
G = 1, CL = 4.7nF

APPLICATION CIRCUITS

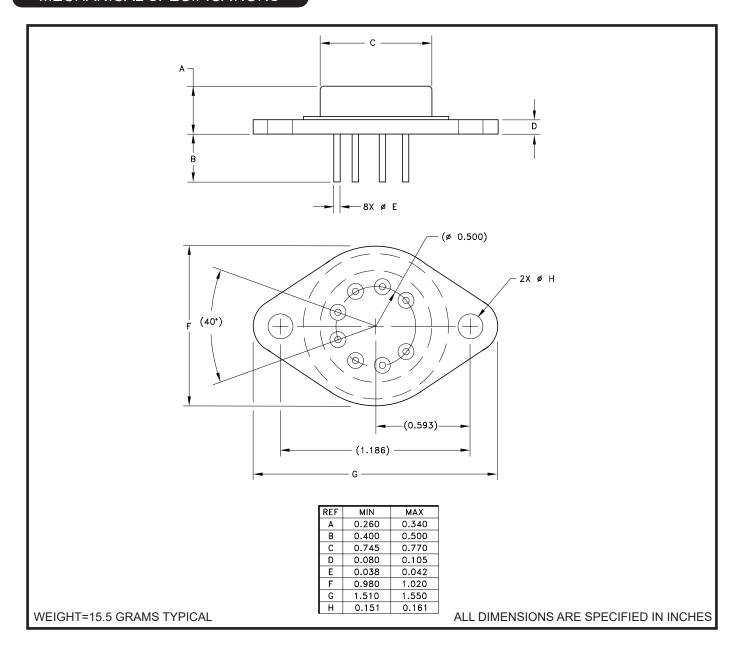








MECHANICAL SPECIFICATIONS



ORDERING INFORMATION

Part Number	Screening Level
MSK2541	Industrial
MSK2541B	MIL-PRF-38534, Class H
5962-9083801HX	DSCC-SMD
5962-9083803HX	DSCC-SMD

REVISION HISTORY

REV	STATUS	DATE	DESCRIPTION
I	Released	07/14	Format updates, assigned form number, added internal solder note, remove E version.
J	Released	09/17	Clarify GBD specification & update format

ANAREN, MSK Products www.anaren.com/msk